

Thematic course: Chemical bath synthesis of metal chalcogenide films. Part 37.

## Chemical bath deposition of ZnSe films with sodium selenosulfate

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### Abstract

Zinc selenide is one of the most perspective materials for creating electroluminescent structures and lasers on its base which irradiate from blue to infrared specter range. Among existing methods of obtaining semiconductor ZnSe layers the most perspective is chemical bath deposition method which excludes unnecessary in high temperature heating, use of complex and expensive equipment for creation of deep vacuum. Analysis of ionic equilibriums in the system “ZnCl<sub>2</sub> – H<sub>2</sub>O – Na<sub>3</sub>Cit” showed that more than 99% of zinc ions in the solution with pH range  $0 \leq \text{pH} \leq 9$  exist in the form of complex with citrate-ion ZnCit<sup>-</sup> and other complex forms of zinc are almost absent. With pH = 10.0-12.5 about 50% of zinc exist in solution in the form of neutral hydroxo complex Zn(OH)<sub>2</sub>. Concentration of Zn(OH)<sub>4</sub><sup>2-</sup> complex in solution prevails with pH > 13. Thermodynamic estimation of boundary conditions of zinc selenide solid phase formation in the reaction system “ZnCl<sub>2</sub> – Na<sub>3</sub>C<sub>6</sub>H<sub>5</sub>O<sub>7</sub> – NH<sub>2</sub>OH·HCl – NaOH – Na<sub>2</sub>SeSO<sub>3</sub>” allowed to conclude that with pH = 10-12.5 the formation of Zn(OH)<sub>2</sub> solid phase on sital substrate is possible. This new surface acts as nucleation center for ZnSe solid phase condensation. Due to it, experimental check of possibility to depose zinc selenide with sodium selenosulfate was carried out in neutral range of pH = 6-7. As a result of carried out experiment of chemical bath deposition from the presented reaction mixture zinc selenide films of orange color and having good adhesion to sital substrate were obtained. Thickness of deposited films reached 800 nm in dependence on deposition conditions. Energy-dispersive elemental analysis established content of main elements in layers, which was on the average for Zn (51.64±1.0 at. %) and Se (48.36±1.0 at. %). It says about lack of halogen in layers in comparison with formula composition. Possibly, it is related with zinc oxygen-containing phase formation Zn(OH)<sub>2</sub>, which can be predicted in calculation. Shown, that freshly deposited zinc selenide layers have p-type conductivity which was established by thermoelectric power sign.

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